

AUTOMOTIVE CURRENT TRANSDUCER OPEN LOOP TECHNOLOGY

HAH1DRW 100-S/SP5, HAH1DRW 200-S/SP5, HAH1DRW 300-S/SP5, HAH1DRW 400-S/SP5, HAH1DRW 500-S/SP5, HAH1DRW 600-S/SP5, HAH1DRW 700-S/SP5, HAH1DRW 800-S/SP5, HAH1DRW 900-S/SP5, HAH1DRW 1000-S/SP5, HAH1DRW 1200-S/SP5, HAH1DRW 1500-S/SP5



Introduction

The HAH1DRW family for the electronic measurement of DC, AC or pulsed currents in high power and low voltage automotive applications with galvanic separation between the primary circuit (high power) and the secondary circuit (electronic circuit).

The HAH1DRW family gives you the choice of having different current measuring ranges in the same housing.

Features

- Ratiometric transducer
- Open Loop transducer using the Hall effect
- · Low voltage application
- Unipolar +5 V DC power supply
- Maximum RMS primary admissible current: defined by busbar to have T < +150 °C
- Operating temperature range: -40 °C < T < 125 °C
- Output voltage: full ratio-metric (in sensitivity and offset).

Special features

- Additional coating of the ASIC pins
- Compressor limiter for M4 screw.

Advantages

- Excellent accuracy
- Very good linearity
- · Very low thermal offset drift
- Very low thermal sensitivity drift
- Galvanic separation
- High frequency bandwidth
- Non intrusive solution.

Automotive applications

- Electrical Power Steering
- Starter Generators
- Converters
- Battery Management
- Motor drive application.

WARRANTY CE ARRIVERS

Principle of HAH1DRW family

The open loop transducers use a Hall effect integrated circuit. The magnetic flux density B, contributing to the rise of the Hall voltage, is generated by the primary current $I_{\rm p}$ to be measured.

The current to be measured I_p is supplied by a current source i.e. battery or generator (Figure 1).

Within the linear region of the hysteresis cycle, ${\it B}$ is proportional to:

$$B(I_{D}) = a \times I_{D}$$

The Hall voltage is thus expressed by:

$$U_{\text{Hall}} = (c_{\text{Hall}} / d) \times I_{\text{Hall}} \times a \times I_{\text{P}}$$

Except for $I_{\rm p}$, all terms of this equation are constant. Therefore:

 $\begin{aligned} U_{\text{Hall}} &= b \times I_{\text{P}} \\ a & \text{constant} \\ b & \text{constant} \\ c_{\text{Hall}} & \text{Hall coefficient} \end{aligned}$

The measurement signal $U_{\mbox{\scriptsize Hall}}$ amplified to supply the user output voltage or current.

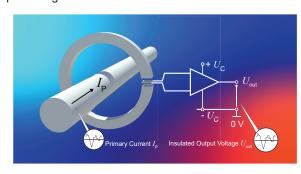
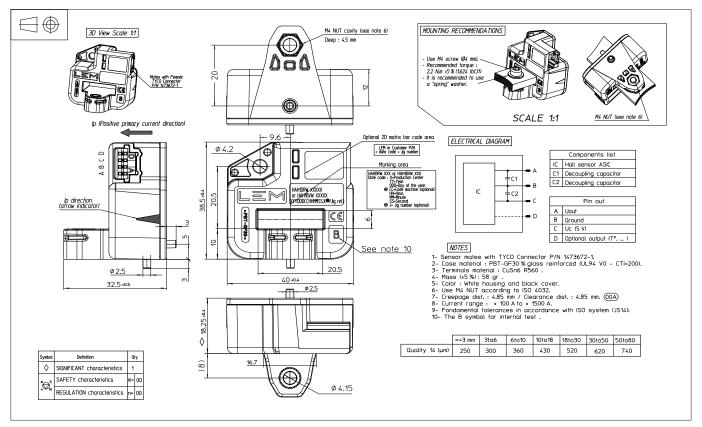


Fig. 1: Principle of the open loop transducer.



Dimensions (in mm)

HAH1DRW 100-S/SP5...1500-S/SP5



Mechanical characteristics

Plastic case
 PBT GF 30

Magnetic core
 FeSi wound core

• Mass 58 g ±5 %

Pins
 Brass tin plated

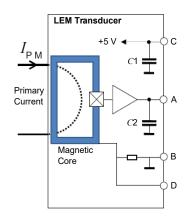
IP level IPx 2.

Mounting recommendation

Connector type
 TYCO connector P/N 1473672-1

Assembly torque max
 2.2 N·m ±5 %

Electronic schematic



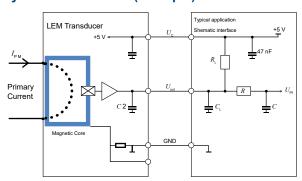
	Components list	
IC	Hall sensor ASIC	
C1	Decoupling capacitor	47 nF
C2	EMC protection capacitor	4.7 nF

	Pin out									
Α	$U_{ m out}$									
В	GND									
С	<i>U</i> _c (5 V)									
D	GND									

Remark

• $U_{\rm out}$ > $U_{\rm o}$ when $I_{\rm p}$ flows in the positive direction (see arrow on drawing).

System architecture (example)



 $C_{\rm L}$ < 2.2 nF EMC protection (optional) RC Low pass filter (optional)

On board diagnostic

 $R_{\rm i} > 10~{\rm k}\Omega$. Resistor for signal line diagnostic (optional)

$U_{ m out}$	Diagnostic
Open circuit	$U_{\mathrm{IN}} = U_{\mathrm{C}}$
Short GND	U _{IN} = 0 V



Absolute ratings (not operating)

HAH1DRW 100-S/SP5...1500-S/SP5

Davamatav	Cumbal	Unit	Specification			Conditions
Parameter	Symbol		Min	Typical	Max	Conditions
Maximum supply voltage	$U_{\mathrm{C}\;\mathrm{max}}$	V	-0.5		8	1)
Ambient storage temperature	T_{Ast}	°C	-40		125	
Electrostatic discharge voltage (HBM)	U_{ESDHBM}	kV			8	
Maximum admissible vibration (random RMS)	$\gamma_{\rm max}$	m·s⁻²			27.1	10 to 1000 Hz, −40 °C to 125 °C
RMS voltage for AC insulation test	U_{d}	kV			2.5	50 Hz, 1 min
Creepage distance	d_{Cp}	mm	4.85			
Clearance	d_{CI}	mm	4.85			
Comparative traking index	CTI		PLC 3			
Maximum output current	I _{out max}	mA	-10		10	
Maximum output voltage	$U_{ m outmax}$	V	-0.5		U _c + 0.5	

Operating characteristics in nominal range (I_{PN})

Downwardow.	Compleal	110014	Specification			Conditions				
Parameter	Symbol	Unit	Min	Typical	Max	Conditions				
		El	ectrical	Data						
Supply voltage	U_{C}	V	4.75	5	5.25					
Ambient operating temperature	T_{A}	°C	-40		125					
Output voltage (Analog)	U_{out}	V	$U_{\text{out}} = ($	U _c / 5) × (U	$(S + S \times I_P)$					
Offset voltage	U_{o}	V		2.5						
Current consumption	I_{C}	mA		20	25					
Load resistance	R_{L}	ΚΩ	10							
Output internal resistance	R_{out}	Ω		1	10					
	Performance Data									
Ratiometricity error	$\varepsilon_{\rm r}$	%		±0.5						
Magnetic offset voltage	U_{OM}	mV		±2		$\textcircled{@}\ U_{\text{C}}$ = 5 V, $\textcircled{@}\ T_{\text{A}}$ = 25 °C				
Linearity error	ε_{L}	%	-1		1	% of full scale				
Average temperature coefficient of U_{OE}	TCU_{OEAV}	mV/°C		±0.04						
Average temperature coefficient of S	TCS _{AV}	%/°C		±0.02						
Delay time to 90 % of the final output value for $I_{\rm PN}$ step	t _{D 90}	μs		2	6	di/dt = 100 A / μs				
Frequency bandwidth	BW	kHz	40			@ -3 dB				
Peak-to-peak noise voltage	$U_{ m nopp}$	mV			14	DC to 1 MHz				
Output RMS noise voltage	U_{no}	mV			2.2					
Phase shift	Δφ	٥	-4		·	DC to 1 KHz				

Note: 1) Exceeding 6.5 V may temporarily reconfigure the device until next power on.



HAH1DRW 100-S/SP5

HAH1DRW 100-S/SP5...1500-S/SP5

Parameter	Cumbal	Unit		Specification		Conditions				
	Symbol		Min	Typical	Max					
Performance Data										
Primary current, measuring range	I_{PM}	Α	-100		100					
Primary nominal RMS current	I_{PN}	Α	-100		100					
Sensitivity	S	mV/A		20		@ T _A = 25 °C				
Sensitivity error	ε_{s}	%		±0.6		@ $T_{\rm A}$ = 25 °C, @ $U_{\rm C}$ = 5 V				
Electrical offset voltage	$U_{{\sf OE}}$	mV		±3		@ $T_{\rm A}$ = 25 °C, @ $U_{\rm C}$ = 5 V				

HAH1DRW 200-S/SP5

Parameter	Symbol	Unit		Specification		Conditions				
	Syllibol		Min	Typical	Max	Conditions				
Performance Data										
Primary current, measuring range	I_{PM}	Α	-200		200					
Primary nominal RMS current	I_{PN}	Α	-200		200					
Sensitivity	S	mV/A		10		@ T _A = 25 °C				
Sensitivity error	ε_{s}	%		±0.6		@ $T_{\rm A}$ = 25 °C, @ $U_{\rm C}$ = 5 V				
Electrical offset voltage	$U_{{\sf OE}}$	mV		±3		@ $T_{\rm A}$ = 25 °C, @ $U_{\rm C}$ = 5 V				

HAH1DRW 300-S/SP5

Parameter	Symbol	Unit		Specification		Conditions				
			Min	Typical	Max	Conditions				
Performance Data										
Primary current, measuring range	I_{PM}	А	-300		300					
Primary nominal RMS current	I_{PN}	А	-300		300					
Sensitivity	S	mV/A		6.667		@ T _A = 25 °C				
Sensitivity error	ε_{s}	%		±0.6		@ $T_{\rm A}$ = 25 °C, @ $U_{\rm C}$ = 5 V				
Electrical offset voltage	$U_{{\sf OE}}$	mV		±3		@ $T_{\rm A}$ = 25 °C, @ $U_{\rm C}$ = 5 V				

HAH1DRW 400-S/SP5

Parameter	Symbol	Unit		Specification	1	Conditions				
			Min	Typical	Max					
Performance Data										
Primary current, measuring range	I_{PM}	А	-400		400					
Primary nominal RMS current	I_{PN}	А	-400		400					
Sensitivity	S	mV/A		5		@ T _A = 25 °C				
Sensitivity error	ε_{s}	%		±0.6		@ $T_{\rm A}$ = 25 °C, @ $U_{\rm C}$ = 5 V				
Electrical offset voltage	$U_{{\sf OE}}$	mV		±3		@ $T_{\rm A}$ = 25 °C, @ $U_{\rm C}$ = 5 V				

HAH1DRW 500-S/SP5

Parameter	Cymhal	Unit		Specification		Conditions			
	Symbol		Min	Typical	Max	Conditions			
Performance Data									
Primary current, measuring range	I_{PM}	А	-500		500				
Primary nominal RMS current	I_{PN}	А	-500		500				
Sensitivity	S	mV/A		4		@ T _A = 25 °C			
Sensitivity error	ε_{s}	%		±0.6		@ $T_{\rm A}$ = 25 °C, @ $U_{\rm C}$ = 5 V			
Electrical offset voltage	$U_{{\scriptscriptstyle{OE}}}$	mV		±3		@ $T_{\rm A}$ = 25 °C, @ $U_{\rm C}$ = 5 V			

HAH1DRW 600-S/SP5

Parameter	Cymah al	Unit		Specification		Conditions				
	Symbol		Min	Typical	Max	Conditions				
Performance Data										
Primary current, measuring range	I_{PM}	А	-600		600					
Primary nominal RMS current	I_{PN}	А	-600		600					
Sensitivity	S	mV/A		3.333		@ T _A = 25 °C				
Sensitivity error	$\varepsilon_{ m s}$	%		±0.6		@ $T_{\rm A}$ = 25 °C, @ $U_{\rm C}$ = 5 V				
Electrical offset voltage	$U_{{\sf OE}}$	mV		±3		@ $T_{\rm A}$ = 25 °C, @ $U_{\rm C}$ = 5 V				

Page 4/9



HAH1DRW 700-S/SP5

HAH1DRW 100-S/SP5...1500-S/SP5

Parameter	Symbol	Unit		Specification		Conditions				
	Syllibol		Min	Typical	Max	Conditions				
Performance Data										
Primary current, measuring range	I_{PM}	Α	-700		700					
Primary nominal RMS current	I_{PN}	Α	-700		700					
Sensitivity	S	mV/A		2.857		@ T _A = 25 °C				
Sensitivity error	ε_{s}	%		±0.6		@ $T_{\rm A}$ = 25 °C, @ $U_{\rm C}$ = 5 V				
Electrical offset voltage	$U_{{\sf OE}}$	mV		±3		@ $T_{\rm A}$ = 25 °C, @ $U_{\rm C}$ = 5 V				

HAH1DRW 800-S/SP5

Parameter	Symbol	Unit		Specification		Conditions
Faranietei	Symbol	Offic	Min	Typical	Max	Conditions
		Perforn	nance Data			
Primary current, measuring range	I_{PM}	Α	-800		800	
Primary nominal RMS current	I_{PN}	Α	-800		800	
Sensitivity	S	mV/A		2.5		@ T _A = 25 °C
Sensitivity error	ε_{s}	%		±0.6		@ $T_{\rm A}$ = 25 °C, @ $U_{\rm C}$ = 5 V
Electrical offset voltage	$U_{{\sf OE}}$	mV		±3		@ $T_{\rm A}$ = 25 °C, @ $U_{\rm C}$ = 5 V

HAH1DRW 900-S/SP5

Danamatan	Company of	1.124	Specification			O and distance
Parameter	Symbol	Unit	Unit Min	Typical	Max	Conditions
		Perforr	nance Data			
Primary current, measuring range	I _{P M}	А	-900		900	
Primary nominal RMS current	I_{PN}	А	-900		900	
Sensitivity	S	mV/A		2.222		@ T _A = 25 °C
Sensitivity error	$\varepsilon_{ m s}$	%		±0.6		@ $T_{\rm A}$ = 25 °C, @ $U_{\rm C}$ = 5 V
Electrical offset voltage	UoE	mV		±3		@ $T_{\rm A}$ = 25 °C, @ $U_{\rm C}$ = 5 V

HAH1DRW 1000-S/SP5

Parameter	Cymhol	Limit	Specification		Conditions	
Parameter	Symbol	Unit	Min	Typical	Max	Conditions
		Perforr	nance Data			
Primary current, measuring range	I_{PM}	А	-1000		1000	
Primary nominal RMS current	I _{PN}	Α	-1000		1000	
Sensitivity	S	mV/A		2		@ T _A = 25 °C
Sensitivity error	ε_{s}	%		±0.7		@ $T_{\rm A}$ = 25 °C, @ $U_{\rm C}$ = 5 V
Electrical offset voltage	UoE	mV		±3		@ $T_{\rm A}$ = 25 °C, @ $U_{\rm C}$ = 5 V

HAH1DRW 1100-S/SP5

Parameter	Cumbal	Unit		Specification Typical Max	Conditions	
ralametei	Symbol	Ullit	Min		Max	Conditions
		Perforr	nance Data			
Primary current, measuring range	I_{PM}	А	-1100		1100	
Primary nominal RMS current	I_{PN}	А	-1100		1100	
Sensitivity	S	mV/A		1.818		@ T _A = 25 °C
Sensitivity error	ε_{s}	%		±0.7		@ $T_{\rm A}$ = 25 °C, @ $U_{\rm C}$ = 5 V
Electrical offset voltage	$U_{{\sf OE}}$	mV		±3		@ $T_{\rm A}$ = 25 °C, @ $U_{\rm C}$ = 5 V

HAH1DRW 1200-S/SP5

Parameter	Cumbal	Linit	Specification		1	Conditions
	Symbol	Unit	Min	Typical Max	Conditions	
		Perforr	nance Data			
Primary current, measuring range	I_{PM}	Α	-1200		1200	
Primary nominal RMS current	I_{PN}	Α	-1200		1200	
Sensitivity	S	mV/A		1.67		@ T _A = 25 °C
Sensitivity error	$\varepsilon_{\rm s}$	%		±0.7		@ $T_{\rm A}$ = 25 °C, @ $U_{\rm C}$ = 5 V
Electrical offset voltage	$U_{{\sf OE}}$	mV		±3		@ $T_{\rm A}$ = 25 °C, @ $U_{\rm C}$ = 5 V

Page 5/9



HAH1DRW 1500-S/SP5

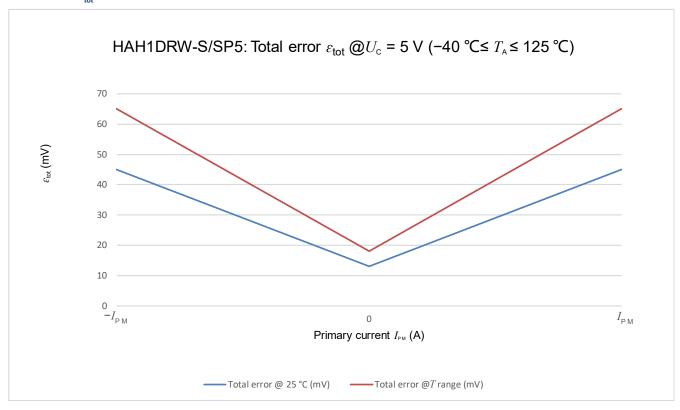
HAH1DRW 100-S/SP5...1500-S/SP5

Parameter	Symbol	Unit	Specification			Conditions	
			Min	Typical	Max	Conditions	
Performance Data							
Primary current, measuring range	I_{PM}	А	-1500		1500		
Primary nominal RMS current	I_{PN}	А	-1500		1500		
Sensitivity	S	mV/A		1.33		@ T _A = 25 °C	
Sensitivity error	ε_{s}	%		±0.9		@ $T_{\rm A}$ = 25 °C, @ $U_{\rm C}$ = 5 V	
Electrical offset voltage	$U_{{\sf OE}}$	mV		±3.6		@ $T_{\rm A}$ = 25 °C, @ $U_{\rm C}$ = 5 V	



HAH1DRW 100-S/SP5...1500-S/SP5

Total error $\varepsilon_{\mbox{\tiny tot}}$

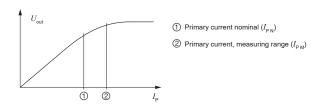


	Total error $arepsilon_{ ext{tot}}$ specification						
$I_{p}\left(A\right)$	$T_{\rm A}$ = 25 °C,	$T_{\rm A}$ = 25 °C, $U_{\rm C}$ = 5 V		5 °C, $U_{\rm c}$ = 5 V			
- I _{P M}	45 mV	2.25 %	65 mV	3.25 %			
0	13 mV	0.65 %	18 mV	0.90 %			
I_{PM}	45 mV	2.25 %	65 mV	3.25 %			



PERFORMANCES PARAMETERS DEFINITIONS

Primary current definition:



Definition of typical, minimum and maximum values:

Minimum and maximum values for specified limiting and safety conditions have to be understood as such as values shown in "typical" graphs. On the other hand, measured values are part of a statistical distribution that can be specified by an interval with upper and lower limits and a probability for measured values to lie within this interval. Unless otherwise stated (e.g. "100 % tested"), the LEM definition for such intervals designated with "min" and "max" is that the probability for values of samples to lie in this interval is 99.73 %. For a normal (Gaussian) distribution, this corresponds to an interval between -3 sigma and +3 sigma. If "typical" values are not obviously mean or average values, those values are defined to delimit intervals with a probability of 68.27 %, corresponding to an interval between -sigma and +sigma for a normal distribution. Typical, minimum and maximum values are determined during the initial characterization of a product.

Output noise voltage:

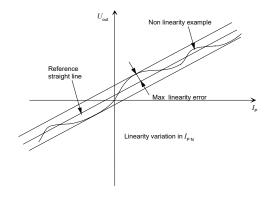
The output voltage noise is the result of the noise floor of the Hall elements and the linear amplifier.

Magnetic offset:

The magnetic offset is the consequence of an any current on the primary side. It's defined after a stated excursion of primary current.

Linearity:

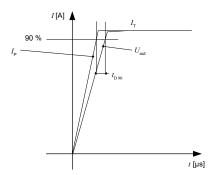
The maximum positive or negative discrepancy with a reference straight line $U_{\rm out}$ = $f(I_{\rm p})$. Unit: linearity (%) expressed with full scale of $I_{\rm P\,N}$.



HAH1DRW 100-S/SP5...1500-S/SP5

Delay time $t_{D 90}$:

The time between the primary current signal (I_{PN}) and the output signal reach at 90 % of its final value.



Sensitivity:

The transducer's sensitivity S is the slope of the straight line $U_{\text{out}} = f(I_{\text{p}})$, it must establish the relation:

$$U_{\text{out}}(I_{\text{P}}) = U_{\text{C}}/5 (S \times I_{\text{P}} + U_{\text{O}})$$

Offset with temperature:

The error of the offset in the operating temperature is the variation of the offset in the temperature considered with the initial offset at 25 °C.

The offset variation $I_{\text{O }T}$ is a maximum variation the offset in the temperature range:

$$I_{OT} = I_{OE} \max - I_{OE} \min$$

The offset drift $TCI_{\text{O E AV}}$ is the $I_{\text{O }T}$ value divided by the temperature range.

Sensitivity with temperature:

The error of the sensitivity in the operating temperature is the relative variation of sensitivity with the temperature considered with the initial offset at 25 °C.

The sensitivity variation $S_{\scriptscriptstyle T}$ is the maximum variation (in ppm or %) of the sensitivity in the temperature range: S_{τ} = (Sensitivity max - Sensitivity min) / Sensitivity at 25 °C. The sensitivity drift $\mathit{TCS}_{\mathsf{AV}}$ is the S_{T} value divided by the temperature range. Deeper and detailed info available is our LEM technical sales offices (www.lem.com).

Offset voltage @ $I_p = 0$ A:

The offset voltage is the output voltage when the primary current is zero. The ideal value of $U_{\rm O}$ is $U_{\rm C}/$ 2. So, the difference of $U_{\rm o}$ – $U_{\rm c}/2$ is called the total offset voltage error. This offset error can be attributed to the electrical offset (due to the resolution of the ASIC quiescent voltage trimming), the magnetic offset, the thermal drift and the thermal hysteresis. Deeper and detailed info available is our LEM technical sales offices (www.lem. com).

Environmental test specifications:

Refer to LEM GROUP test plan laboratory CO.11.11.515.0 with "Tracking Test Plan Auto" sheet.



Environmental test specifications:

HAH1DRW 100-S/SP5...1500-S/SP5

Refer to LEM GROUP test plan laboratory CO.11.11.515.0 with "Tracking_Test Plan_Auto" sheet.

Name	Standard
CHARACTERIZATIO	N @ 25 °C (initial)
Sensitivity / Accuracy / Total error	LEM 98.20.00.574.0
Offset / Electrical Offset / Magnetic Offset	LEM 98.20.00.573.0
Linearity error	LEM 98.20.00.370.0
Current Consumption	LEM 98.20.00.579.0
CHARACTERIZATION	
Sensitivity / Accuracy / Total error	LEM 98.20.00.574.0
T °C variation of / Temperature Coefficient of G	LEM 98.20.00.574.0
Offset / Electrical Offset / Magnetic Offset	LEM 98.20.00.573.0
T °C variation of /Temperature Coefficient of Offset	LEM 98.20.00.573.0
Linearity error	LEM 98.20.00.370.0
Current Consumption	LEM 98.20.00.579.0
ELECTRICAL TI	
Phase delay check	100 Hz to 100 KHz @ 20 A peak
Noise measurement	Sweep from DC to 1 MHz
Delay time di/dt	100 A/ μ s. I pulse = $I_{P \text{ max}}$
dv/dt	2000 V/µs. U = 2000 V
Dielectric Withstand Voltage test	2500 V AC / 1 min / 50 Hz
Insulation Resistance test	500 V DC, time = 60 s $R_{\rm INS} \ge$ 500 M Ω Minimum
ENVIRONMENTAL T	ESTS (CLIMATIC)
	ISO 16750-4 § 5.3.2 (04/2010)
	500 cycles (500 hours),
Thermal shock	30 min @ -40 °C // 30 min @ +125 °C
	$U_{\rm C}$ not connected, $I_{\rm P}$ = 0
Steady state T°C Humidity bias life test	JESD 22-A 101 (03/2009)
MECHANICA	AL TESTS
Vibration Random in <i>T</i> °C	ISO 16750-3 § 4.1.2.4(12/2012) 27.1 m/s², 8 h/axe 10 Hz -1000 Hz
	ISO 16750-3 § 4.2.2 (12/2012)
	50 g/ 6 ms Half Sine @ 25 °C
Shocks	10 shocks of each direction (Total: 60)
	$U_{\rm C}$ not connected, $I_{\rm P}$ = 0
Free Fall (Device not packaged)	IEC 60068-2-31 §5.2: method 1 (05/2008)
EM	c
Immunity to ElectroStatic Discharges (Handling of devices)	ISO 10605 (07/2008)
Immunity to Conducted disturbances (BCI)	ISO 11452-4 (12/2011)
Emission Radiated (ALSE)	CISPR 25 (03/2008)
FINAL CHARAC	CTERIZATION
= 0	
Characterization @ 25 °C Characterization with T °C	